PS2381-1

R08DS0134EJ0200
Rev.2.00
Oct 30, 2015

4-PIN LSOP PHOTOCOUPLER OPERATING AMBIENT TEMPERATURE 115°C

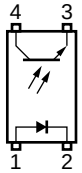
DESCRIPTION

The PS2381-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.
This package is mounted in a plastic 4-LSOP (Long Mini-Flat Small Outline Package) for high density applications.
The package has shield effect to cut off ambient light.

FEATURES

- Operating ambient temperature: 115°C
- Isolation distance (0.4 mm MIN.)
- High isolation voltage (BV = 5 000 Vr.m.s.)
- 4-pin LSOP (Long Mini-Flat Small Outline Package) type
- High-speed switching (tr = 4 μs TYP., tf = 5 μs TYP.)
- Embossed tape product: PS2381-1-F3: 3 000 pcs/reel
- Pb-Free product
- Safety standards
  - UL approved: No. E72422
  - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
  - SEMKO approved (EN 60065, EN 60950)
  - DIN EN 60747-5-5 (VDE 0884-5) approved (Option)
  - CQC approved (GB8898, GB4943)

PIN CONNECTION
(Top View)

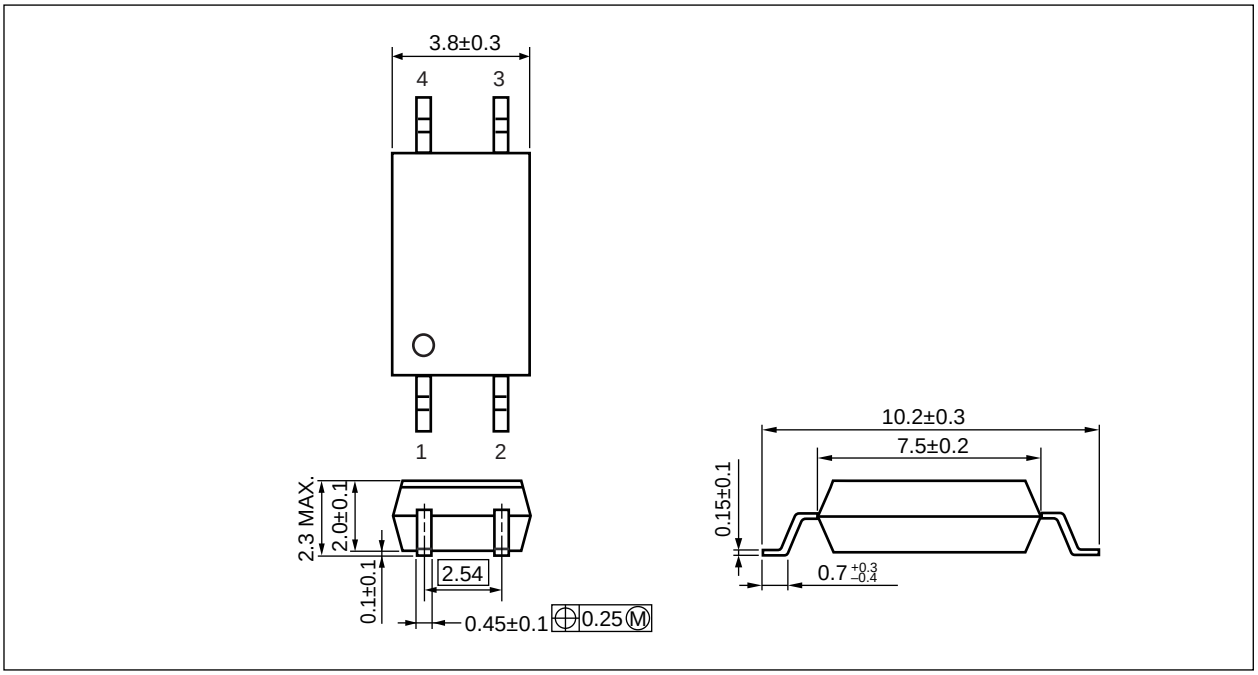


1. Anode
2. Cathode
3. Emitter
4. Collector

APPLICATIONS

- Power supply
- FA/OA equipment

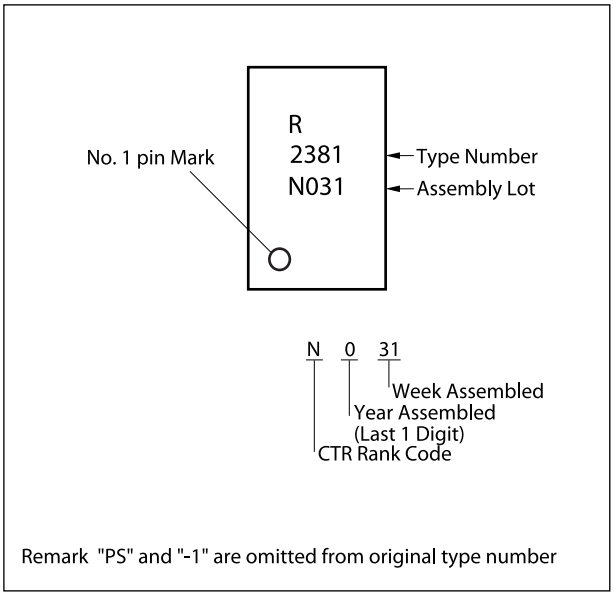
PACKAGE DIMENSIONS (Unit: mm)



PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	8 mm
Outer Creepage Distance	8 mm
Isolation Distance	0.4 mm

MARKING EXAMPLE



ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification etc.	Packing Style	Safety Standard Approval	Application Part Number*1
PS2381-1	PS2381-1Y-AX	Pb-Free and Halogen Free	20 pcs (Tape 20 pcs cut)	Standard products (UL, CSA, SEMKO, CQC approved)	PS2381-1
PS2381-1-F3	PS2381-1Y-F3-AX		Embossed Tape 3 000 pcs/reel		
PS2381-1-V	PS2381-1Y-V-AX		20 pcs (Tape 20 pcs cut)	UL, CSA, SEMKO, CQC approved DIN EN 60747-5-5 (VDE 0884-5) approved (Option)	
PS2381-1-V-F3	PS2381-1Y-V-F3-AX		Embossed Tape 3 000 pcs/reel		

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	I_F	60	mA
	Reverse Voltage	V_R	6	V
	Power Dissipation Derating*1	ΔP_D/°C	1.0	mW/°C
	Power Dissipation	P_D	100	mW
	Peak Forward Current*2	I_{FP}	1.5	A
Transistor	Collector to Emitter Voltage	V_{CEO}	80	V
	Emitter to Collector Voltage	V_{ECO}	7	V
	Collector Current	I_C	50	mA
	Power Dissipation Derating*1	ΔP_C/°C	1.5	mW/°C
	Power Dissipation	P_C	150	mW
Isolation Voltage*3		BV	5 000	Vr.m.s.
Total Power Dissipation		P_T	250	mW
Operating Ambient Temperature		T_A	–40 to +115	°C
Storage Temperature		T_{stg}	–40 to +125	°C

Notes: *1. Derating from T_A = 25°C.

*2. PW = 100 μs, Duty Cycle = 1%

*3. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output.
Pins 1-2 shorted together, 3-4 shorted together.

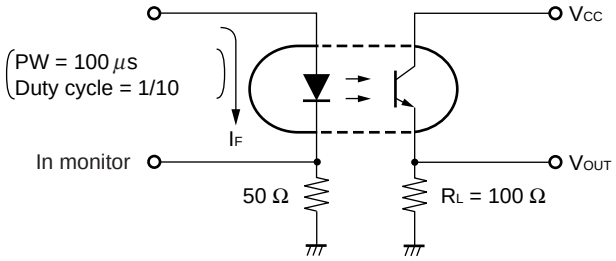
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

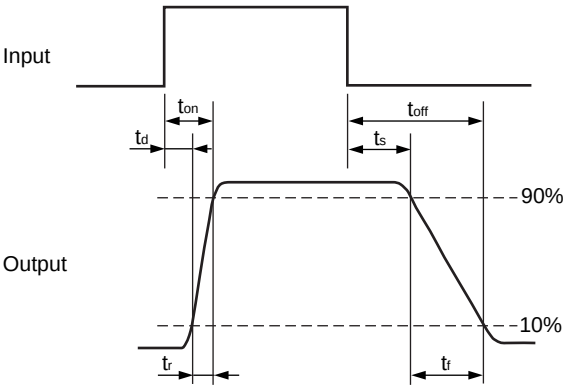
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = 5 mA		1.1	1.4	V
	Reverse Current	I_R	V_R = 5 V			5	μA
	Terminal Capacitance	C_t	V = 0 V, f = 1 MHz		15		pF
Transistor	Collector to Emitter Dark Current	I_{CEO}	I_F = 0 mA, V_{CE} = 24 V			100	nA
Coupled	Current Transfer Ratio (I_C/I_F) *1	CTR	I_F = 5 mA, V_{CE} = 5 V	50	100	400	%
			I_F = 1 mA, V_{CE} = 5 V	10	50		
	Collector Saturation Voltage	$V_{CE (sat)}$	I_F = 10 mA, I_C = 2 mA			0.3	V
	Isolation Resistance	R_{I-O}	V_{I-O} = 1 kV_{DC}	10^{11}			Ω
	Isolation Capacitance	C_{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time*2	t_r	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω		4		μs
	Fall Time*2	t_f			5		

Notes: *1. CTR rank

CTR rank	CTR (%)	Conditions
W	130 to 260	I_F = 5 mA, V_{CE} = 5 V
	20 to	I_F = 1 mA, V_{CE} = 5 V
L	100 to 300	I_F = 5 mA, V_{CE} = 5 V
	20 to	I_F = 1 mA, V_{CE} = 5 V
M	50 to 150	I_F = 5 mA, V_{CE} = 5 V
	10 to	I_F = 1 mA, V_{CE} = 5 V
N	50 to 400	I_F = 5 mA, V_{CE} = 5 V
	10 to	I_F = 1 mA, V_{CE} = 5 V

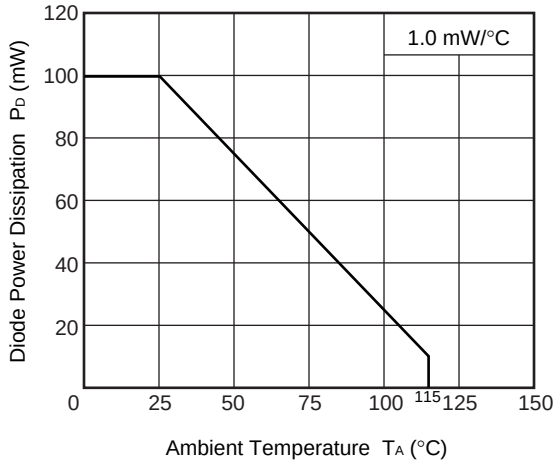
*2. Test circuit for switching time



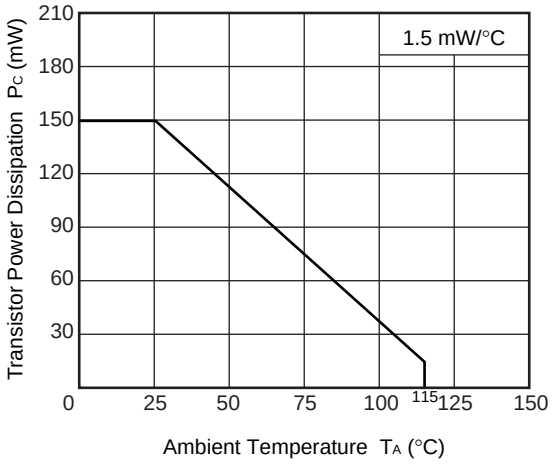


TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

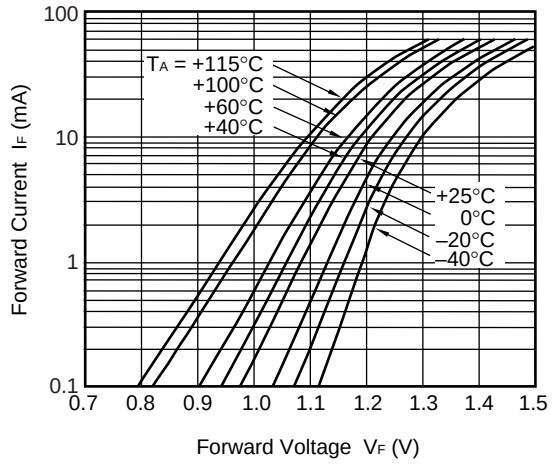
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



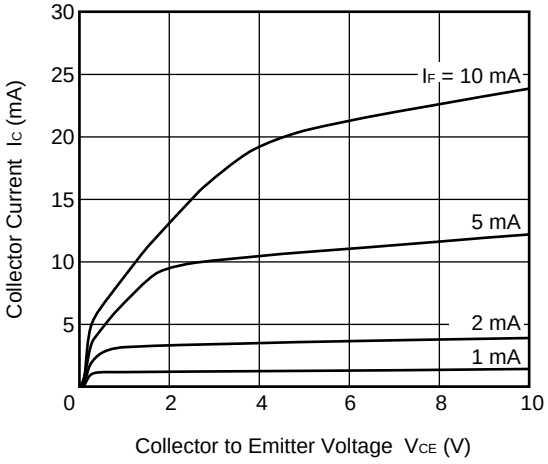
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



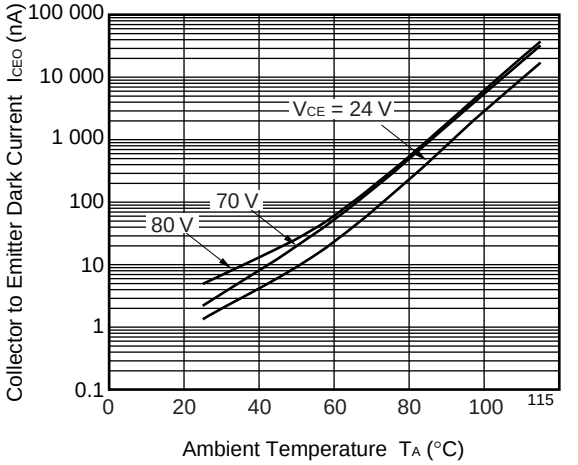
FORWARD CURRENT vs. FORWARD VOLTAGE



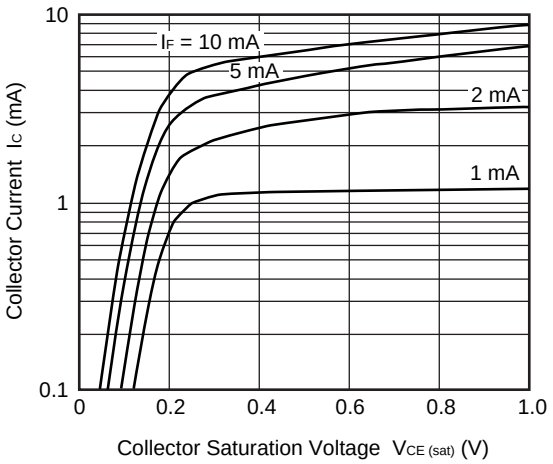
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



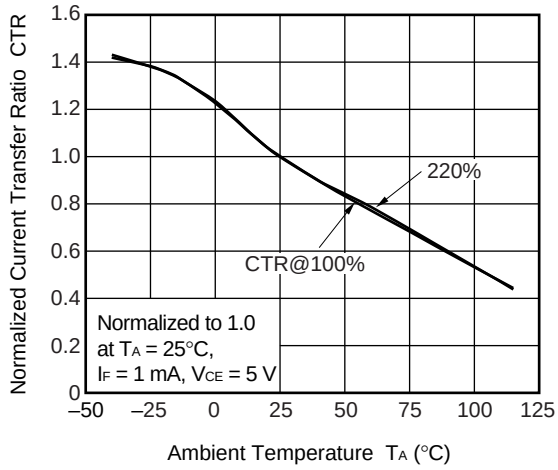
COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE



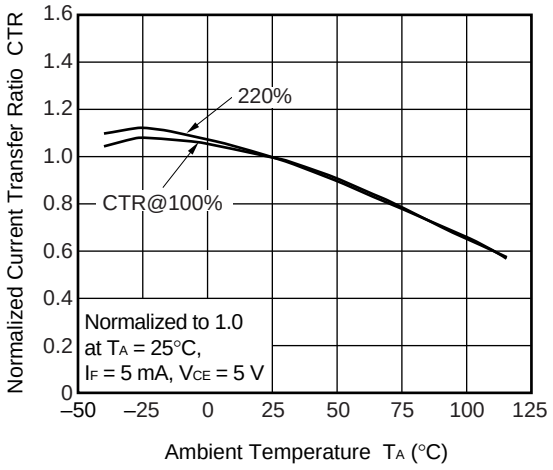
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



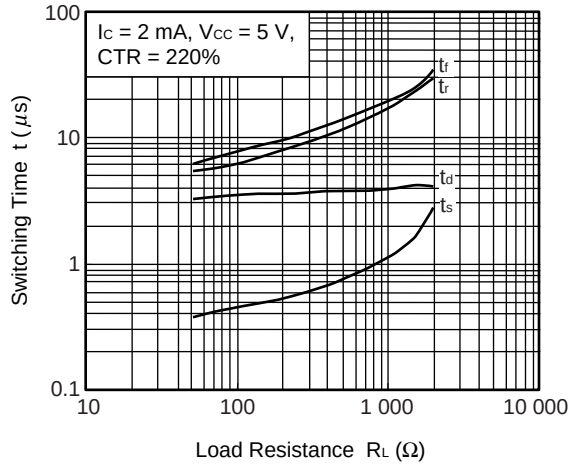
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



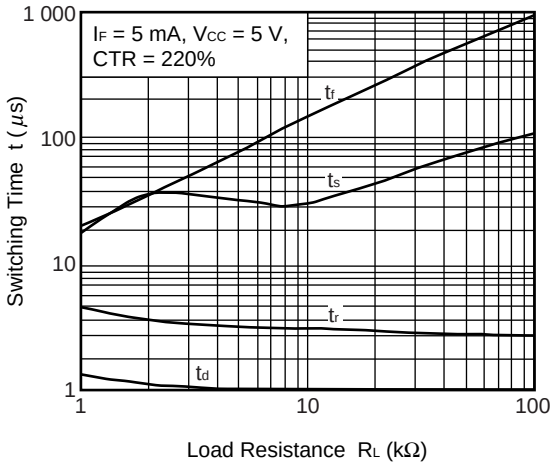
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



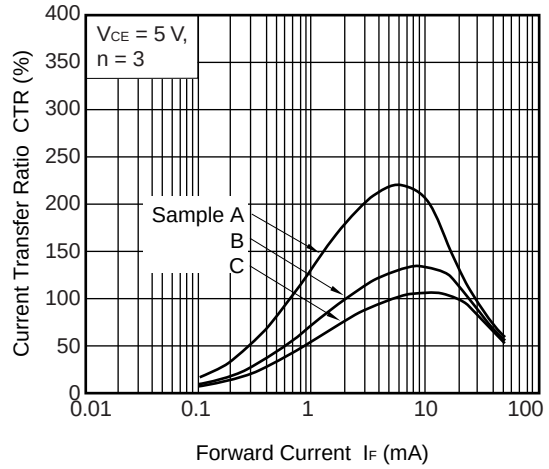
SWITCHING TIME vs. LOAD RESISTANCE



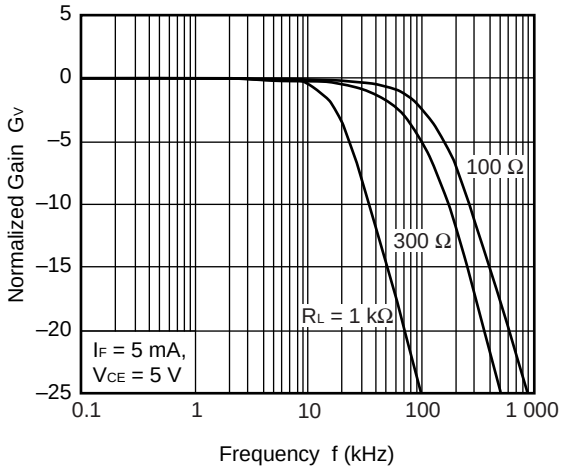
SWITCHING TIME vs. LOAD RESISTANCE



CURRENT TRANSFER RATIO vs. FORWARD CURRENT



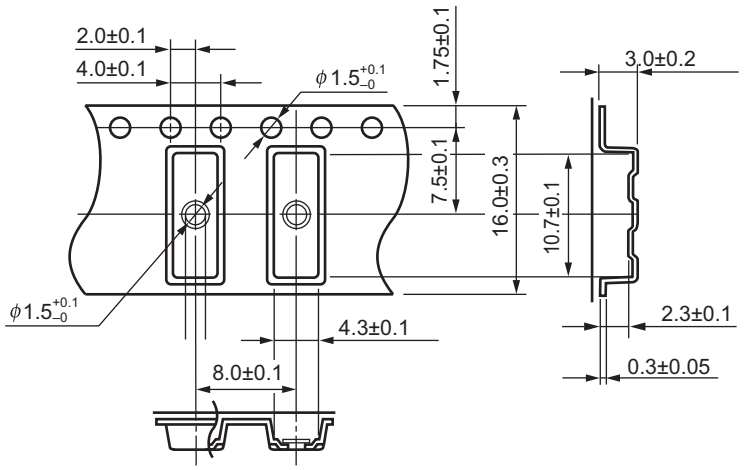
FREQUENCY RESPONSE



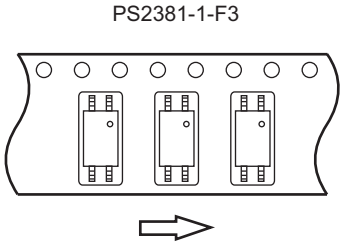
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

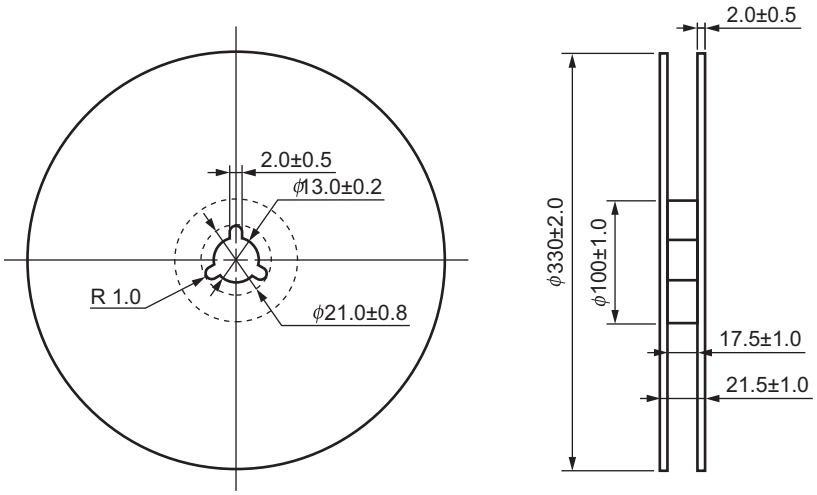
Outline and Dimensions (Tape)



Tape Direction

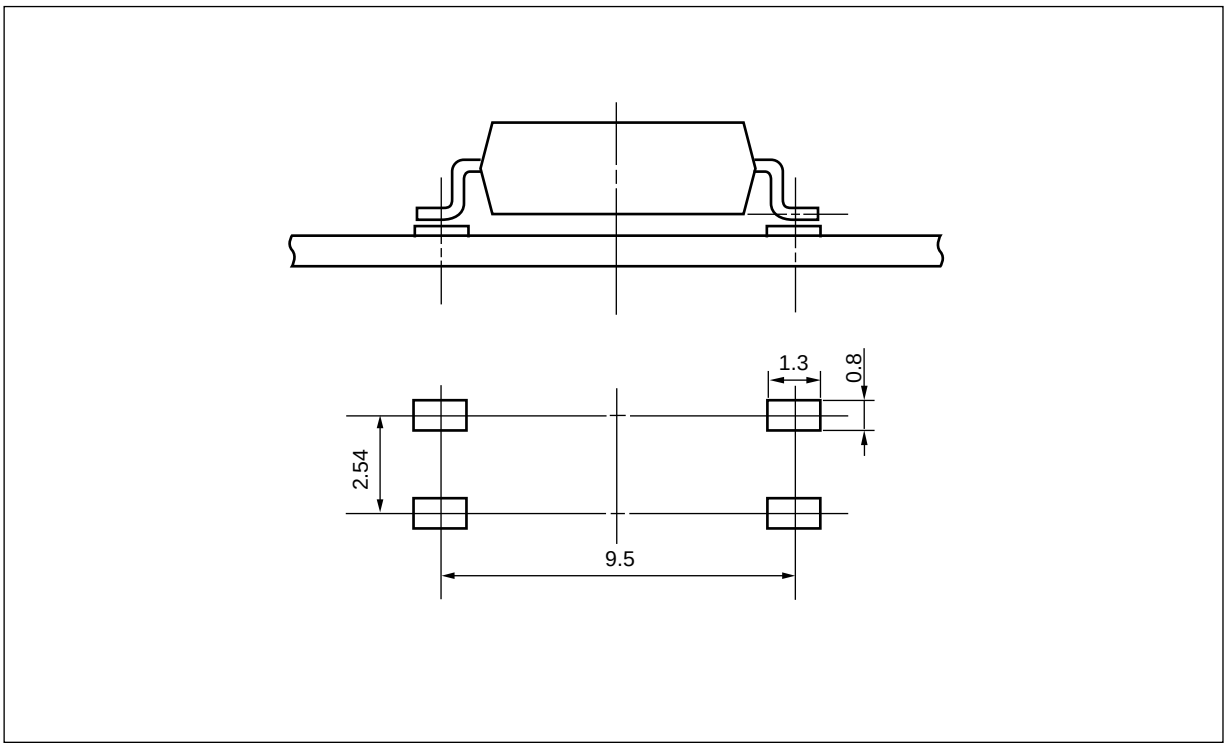


Outline and Dimensions (Reel)



Packing: 3 000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

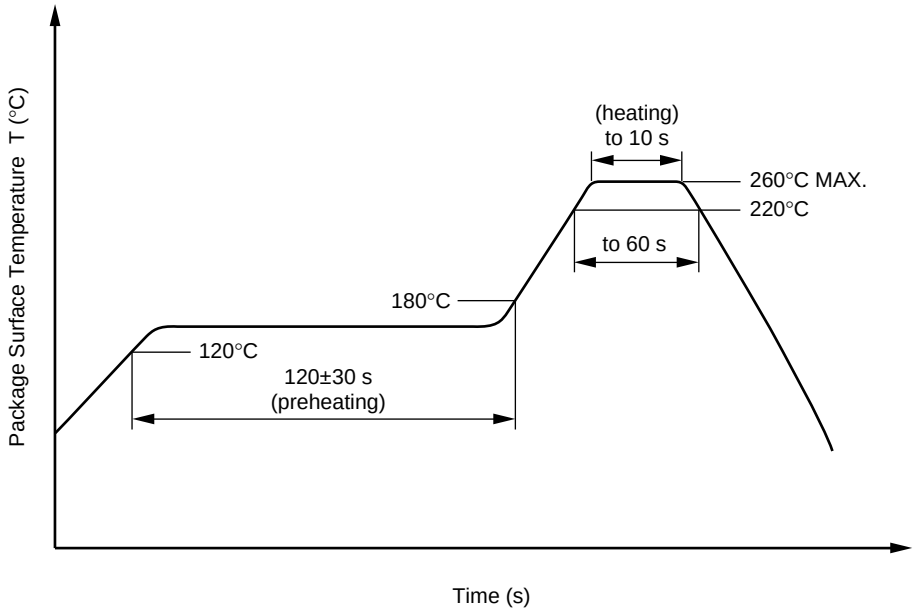
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature	260°C or below (package surface temperature)
• Time of peak reflow temperature	10 seconds or less
• Time of temperature higher than 220°C	60 seconds or less
• Time to preheat temperature from 120 to 180°C	120 ± 30 s
• Number of reflows	Three
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature	260°C or below (molten solder temperature)
• Time	10 seconds or less
• Preheating conditions	120°C or below (package surface temperature)
• Number of times	One (Allowed to be dipped in solder including plastic mold portion.)
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by soldering iron

• Peak temperature (lead part temperature)	350°C or below
• Time (each pins)	3 seconds or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.
(b) Please be sure that the temperature of the package would not be heated over 100°C.

(4) Cautions

• Fluxes	Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/115/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}$, $P_d < 5$ pC	 U_{IORM} U_{pr}	 1 130 1 808	 V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}$, $P_d < 5$ pC	U_{pr}	2 119	V_{peak}
Highest permissible overvoltage	U_{TR}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	T_{stg}	–40 to +125	°C
Operating temperature range	T_A	–40 to +115	°C
Isolation resistance, minimum value V_{IO} = 500 V dc at T_A = 25°C V_{IO} = 500 V dc at T_A MAX. at least 100°C	 Ris MIN. Ris MIN.	 10^{12} 10^{11}	 Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F, Psi = 0) Power (output or total power dissipation) Isolation resistance V_{IO} = 500 V dc at T_A = Tsi	 Tsi Isi Psi Ris MIN.	 175 400 700 10^9	 °C mA mW Ω

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points. • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.

Revision History	PS2381-1 Data Sheet

Rev.	Date	Description	
		Page	Summary
2.00	Oct 30, 2015	–	First edition issued

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